Unit in mm

TOSHIBA DIODE SILICON EPITAXIAL PLANAR TYPE

155302

ULTRA HIGH SPEED SWITCHING APPLICATIONS.

Small Package : SC-70

Low Forward Voltage $: V_{F(3)} = 0.90V \text{ (Typ.)}$

Fast Reverse Recovery Time: trr=1.6ns (Typ.)

Small Total Capacitance $: C_T = 0.9 pF (Typ.)$

MAXIMUM RATINGS (Ta = 25°C)

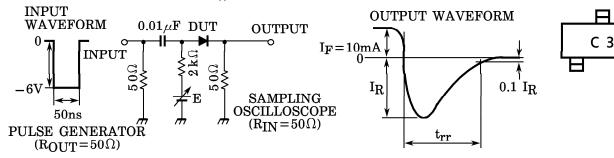
CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	v_{RM}	85	V
Reverse Voltage	$V_{\mathbf{R}}$	80	V
Maximum (Peak) Forward Current	I_{FM}	300 (*)	mA
Average Forward Current	IO	100 (*)	mA
Surge Current (10ms)	I_{FSM}	2 (*)	A
Power Dissipation	P	100	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

(*) Unit Rating. Total Rating=Unit Rating×0.7

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	$V_{F(1)}$	I _F =1mA	_	0.60	_	V
	$V_{F(2)}$	$I_{\mathbf{F}} = 10 \text{mA}$	_	0.72	_	
	$V_{F(3)}$	$I_{\rm F}$ =100mA		0.90	1.20	
Reverse Current	$I_{R(1)}$	$V_R = 30V$		_	0.1	μ A
	$I_{R(2)}$	$V_R=80V$	_	_	0.5	
Total Capacitance	C_{T}	$V_R=0$, f=1MHz	_	0.9	3.0	рF
Reverse Recovery Time	$t_{ m rr}$	$I_{ m F}$ = 10mA, Fig.1	_	1.6	4.0	ns

Fig.1 REVERSE RECOVERY TIME (t_{rr}) TEST CIRCUIT

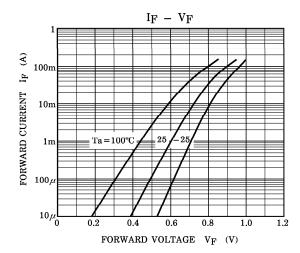


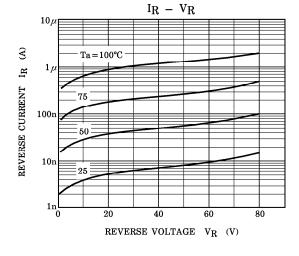
 2.1 ± 0.1 1.25 ± 0.1 1.3 ± 0.1 2.0 ± 0.2 ANODE 1 CATHODE 2 2. ANODE 2 USM CATHODE 1 **JEDEC EIAJ** SC-70 TOSHIBA 1-2P1C

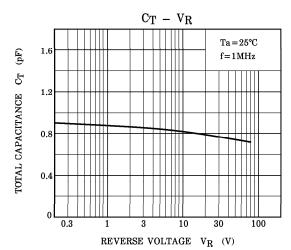
Weight: 0.006g

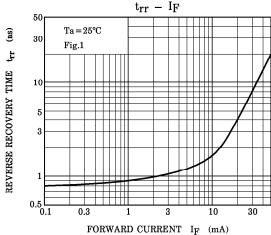
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